



# SDM10U45LP

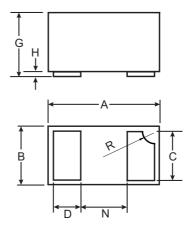
## SURFACE MOUNT SCHOTTKY BARRIER DIODE

#### **Features**

- Low Forward Voltage Drop
- Guard Ring Die Construction for **Transient Protection**
- Low Capacitance
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: DFN1006-2
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: Cathode Dot
- Terminals: Finish NiPdAu annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Marking Code: LJ, Dot Denotes Cathode Side
- Ordering Information: See Last Page
- Weight: 0.001 grams



DFN1006-2				
Dim	Min Max T		Тур	
Α	0.95	1.075	1.00	
В	0.55	0.675	0.60	
С	0.45	0.55	0.50	
D	0.20	0.30	0.25	
G	0.47	0.53	0.50	
Н	0	0.05	0.03	
N	_	_	0.40	
R	0.05	0.15	0.10	
All Dimensions in mm				

## Maximum Ratings @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Maximum Peak Reverse Voltage	V <sub>RM</sub>	45	V
Reverse Voltage	V <sub>R</sub>	40	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	28	V
Average Forward Current	I <sub>O</sub>	100	mA
Maximum (Peak) Forward Current	I <sub>FM</sub>	300	mA
Non-Repetitive Peak Forward Surge Current @ t ≤ 10ms	I <sub>FSM</sub>	1	А
Operating and Storage Temperature Range	T <sub>j</sub> , T <sub>STG</sub>	-40 to +125	°C

## Thermal Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation	Pd	250	mW
Thermal Resistance, Ambient Air	$R_{ heta JA}$	400	°C/W

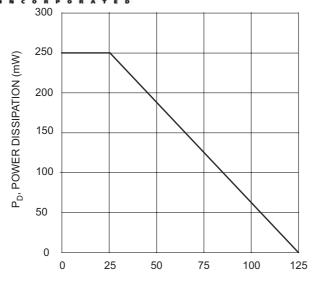
## Electrical Characteristics @ TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions
Reverse Breakdown Voltage (Note 3)	V <sub>(BR)R</sub>	30	_	_	V	I <sub>R</sub> = 100μA
Forward Voltage Drop	V <sub>F</sub>	_	280 360 470 580	550 800	mV	I <sub>F</sub> = 1.0mA I <sub>F</sub> = 15mA I <sub>F</sub> = 50mA I <sub>F</sub> = 100mA
Reverse Current (Note 3)	I <sub>R</sub>	_	_	1.0	μΑ	V <sub>R</sub> = 25V
Total Capacitance	Ст	_	7	15	pF	V <sub>R</sub> = 10V, f = 1.0 MHz

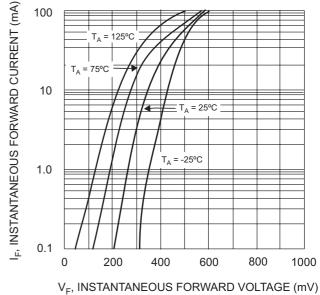
1. No purposefully added lead.

- 2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.
- 3. Short duration pulse test used so as to minimize self-heating effect.

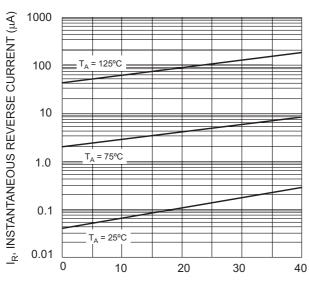




T<sub>A</sub>, AMBIENT TEMPERATURE (°C) Fig. 1 Power Derating Curve



V<sub>F</sub>, INSTANTANEOUS FORWARD VOLTAGE (mV) Fig. 2 Typical Forward Characteristics



 $V_{R}$ , INSTANTANEOUS REVERSE VOLTAGE (V) Fig. 3 Typical Reverse Characteristics

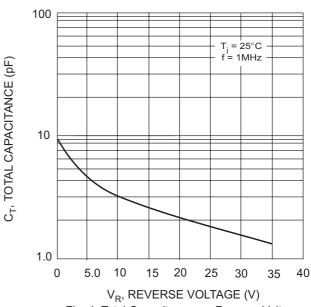


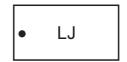
Fig. 4 Total Capacitance vs. Reverse Voltage

## Ordering Information (Note 4)

Device	Packaging	Shipping
SDM10U45LP-7	DFN1006-2	3000/Tape & Reel

Note: 4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

# **Marking Information**



LJ = Product Type Marking Code, Dot Denotes Cathode Side



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